High-temperature Raman spectroscopic study of ilmenite-type MgTiO3 and MgGeO3

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[Introduction]

Ilmenite-type MgSiO3 is a high pressure polymorph of enstatite, and characterized by a relatively narrow stability field in the 20-24 GPa, 1100-2000 degrees C range. Since MgSiO3-ilmenite is stable at low temperature, it is considered to be candidate component in 600-700 km of subducting slabs. It is important for earth science to understand its crystal structure on the basis of lattice vibrations at high pressure and temperature. High-pressure and high-temperature Raman spectra of ilmenite-type MgSiO3 have already been collected up to 7 GPa and 1030 K, respectively (Reynard and Rubie (1996) Am. Mineral.). In this study, we conducted a high-temperature Raman spectroscopic study of ilmenite-type MgTiO3 and MgGeO3 that have different pressure stability fields from MgSiO3. From the point of elasticity and bonding energy, we investigate the behavior of MgTiO3 and MgGeO3 at high temperature and compare structures of ilmenite that has different compositions.

[Experimental methods]

High-temperature experiments were performed using a Pt-electric resistant heater. Temperature was monitored with chromel-almel thermocouples. Raman spectra were obtained using a NRS2100 triple microspectrometer equipped with Ar ion laser (operating at 514.5 nm and 80 mW (for MgTiO3), 70 mW (for MgGeO3)). Raman spectra were collected with an exposure time of 5 sec (for MgTiO3), 30 sec (for MgGeO3) every 100 degrees C from room temperature to 500 degrees C.

[Results and discussion]

At ambient conditions, we observed nine (for MgTiO3) and eight (for MgGeO3) Raman bands, respectively. With increasing temperature, each band shifted to lower wavenumber. These phenomena can interpret that bonding energies between atoms become weaker and bonding distances become longer with increasing temperature. As a result, MgTiO3 and MgGeO3 expanded. With decreasing temperature from 500 degrees C, each band shifted to higher wavenumber. Thus, no hysteresis was observed. Raman bands of MgGeO3 shifted more than those of MgTiO3, that is, MgGeO3 expanded much at the same temperature. This is because a mass number of Ge is larger than that of Ti.

From room temperature to 500 degrees C, we observed no softmodes and no dramatically structural change of ilmenite-type MgTiO3 and MgGeO3. Thus, their stabilities are maintained.